SIEMENS

Data sheet 3RF2340-1AA24



Solid-state contactor 1-phase 3RF2 AC 51 / 40 A / 40 $^{\circ}\text{C}$ 48-460 V / 110-230 V AC screw terminal

| product brand name | SIRIUS |
|---|--|
| product designation | solid-state contactor |
| design of the product | single-phase |
| product type designation | 3RF23 |
| manufacturer's article number | |
| _1 of the accessories that can be ordered | 3RF2900-3PA88 |
| _4 of the accessories that can be ordered | 3RF2950-0GA36 |
| product designation | |
| _1 of the accessories that can be ordered | terminal cover |
| _4 of the accessories that can be ordered | load monitoring |
| General technical data | |
| product function | zero-point switching |
| power loss [W] for rated value of the current | |
| at AC in hot operating state | 44 W |
| at AC in hot operating state per pole | 44 W |
| without load current share typical | 3.5 W |
| insulation voltage rated value | 600 V |
| degree of pollution | 3 |
| type of voltage | |
| of the operating voltage | AC |
| of the control supply voltage | AC |
| surge voltage resistance of main circuit rated value | 6 kV |
| protection class IP | IP20 |
| protection class IP on the front according to IEC 60529 | IP20 |
| shock resistance according to IEC 60068-2-27 | 15g / 11 ms |
| vibration resistance according to IEC 60068-2-6 | 2g |
| reference code according to IEC 81346-2 | Q |
| Substance Prohibitance (Date) | 07/01/2006 |
| SVHC substance name | Lead - 7439-92-1 Lead monoxide (lead oxide) - 1317-36-8 Dibutylbis(pentane-2,4-dionato-O,O')tin - 22673-19-4 |
| Weight | 0.445 kg |
| Main circuit | |
| number of poles for main current circuit | 1 |
| number of NO contacts for main contacts | 1 |
| number of NC contacts for main contacts | 0 |
| type of voltage of the operating voltage | AC |
| operating voltage | |
| • at AC | |
| — at 50 Hz rated value | 48 460 V |
| — at 60 Hz rated value | 48 460 V |

| operating frequency rated value | 50 60 Hz |
|---|--|
| operating frequency fated value operating range relative to the operating voltage at AC | 00 00 I IZ |
| at 50 Hz | 40 |
| | 40 506 V |
| • at 60 Hz | 40 506 V |
| operational current | 40.4 |
| at AC-51 rated value | 40 A |
| • at AC-51 according to IEC 60947-4-3 | 33 A |
| according to UL 508 rated value | 36 A |
| operational current minimum | 500 mA |
| rate of voltage rise at the thyristor for main contacts maximum permissible | 1 000 V/μs |
| blocking voltage at the thyristor for main contacts maximum permissible | 1 200 V |
| reverse current of the thyristor | 10 mA |
| derating temperature | 40 °C |
| surge current resistance rated value | 1 200 A |
| I2t value maximum | 7 200 A²·s |
| Control circuit/ Control | |
| type of voltage of the control supply voltage | AC |
| control supply voltage 1 at AC | |
| • at 50 Hz | 110 230 V |
| • at 60 Hz | 110 230 V |
| control supply voltage frequency | |
| • 1 rated value | 50 Hz |
| • 2 rated value | 60 Hz |
| control supply voltage at AC | |
| at 50 Hz full-scale value for signal<0> recognition | 40 V |
| at 60 Hz full-scale value for signal 40 recognition | 40 V |
| control supply voltage | 40 V |
| | 90 V |
| at AC initial value for signal <1> detection | 5 Hz |
| symmetrical line frequency tolerance | 3 NZ |
| control current at minimum control supply voltage | 0 4 |
| • at AC | 2 mA |
| control current at AC rated value | 15 mA |
| ON-delay time | 40 ms; additionally max. one half-wave |
| OFF-delay time | 40 ms; additionally max. one half-wave |
| Auxiliary circuit | |
| type of switching contact | normally open contact (NO) |
| number of NC contacts for auxiliary contacts | 0 |
| number of NO contacts for auxiliary contacts | 0 |
| number of CO contacts for auxiliary contacts | 0 |
| Installation/ mounting/ dimensions | |
| fastening method side-by-side mounting | Yes |
| fastening method | screw fixing and snap-on mounting on standard mounting rail 35 mm according to IEC 60715 |
| design of the thread of the screw for securing the equipment | M4 |
| height | 100 mm |
| width | 67 mm |
| depth | 141 mm |
| Connections/ Terminals | |
| product component removable terminal for auxiliary and control circuit | Yes |
| type of electrical connection | |
| for main current circuit | screw-type terminals |
| | screw type terminals |
| for auxiliary and control circuit tune of connectable conductor group positions | screw-type terminals |
| type of connectable conductor cross-sections | |
| • for main contacts | 0 (45 05 3) 0 (05 0 3) |
| — solid | 2x (1.5 2.5 mm²), 2x (2.5 6 mm²) |
| finely stranded with core end processing | DE |
| | 2x (1 2.5 mm²), 2x (2.5 6 mm²), 1x 10 mm² |
| for AWG cables for main contacts connectable conductor cross-section for main contacts | 2x (14 10) |

| solid or stranded | 1.5 6 mm² |
|---|--|
| finely stranded with core end processing | 1 10 mm² |
| type of connectable conductor cross-sections | |
| for auxiliary and control contacts | |
| — solid | 1x (0.5 2.5 mm²), 2x (0.5 1.0 mm²) |
| finely stranded with core end processing | 1x (0.5 2.5 mm²), 2x (0.5 1.0 mm²) |
| finely stranded without core end processing | 1x (0.5 2.5 mm²), 2x (0.5 1.0 mm²) |
| for AWG cables for auxiliary and control contacts | 1x (AWG 20 12) |
| AWG number as coded connectable conductor cross section for main contacts | 10 14 |
| tightening torque | |
| for main contacts with screw-type terminals | 2 2.5 N·m |
| for auxiliary and control contacts with screw-type terminals | 0.5 0.6 N·m |
| tightening torque [lbf·in] | |
| for main contacts with screw-type terminals | 18 22 lbf·in |
| for auxiliary and control contacts with screw-type terminals | 4.5 5.3 lbf·in |
| design of the thread of the connection screw | |
| • for main contacts | M4 |
| of the auxiliary and control contacts | M3 |
| stripped length of the cable | |
| for main contacts | 7 mm |
| for auxiliary and control contacts | 7 mm |
| Electrical Safety | |
| protection class IP on the front according to IEC 60529 | IP20 |
| touch protection on the front according to IEC 60529 | finger-safe, for vertical contact from the front |
| Ambient conditions | |
| installation altitude at height above sea level maximum | 1 000 m |
| ambient temperature | |
| during operation | -25 +60 °C |
| during operation during storage | -55 +80 °C |
| | |
| | |
| Electromagnetic compatibility conducted interference | |
| Electromagnetic compatibility conducted interference | 2 kV / 5 kHz behavior criterion 2 |
| Electromagnetic compatibility conducted interference • due to burst according to IEC 61000-4-4 | 2 kV / 5 kHz behavior criterion 2 |
| Electromagnetic compatibility conducted interference • due to burst according to IEC 61000-4-4 • due to conductor-earth surge according to IEC 61000-4-5 | 2 kV behavior criterion 2 |
| Electromagnetic compatibility conducted interference • due to burst according to IEC 61000-4-4 | |
| Electromagnetic compatibility conducted interference • due to burst according to IEC 61000-4-4 • due to conductor-earth surge according to IEC 61000-4-5 • due to conductor-conductor surge according to IEC | 2 kV behavior criterion 2 |
| Electromagnetic compatibility conducted interference • due to burst according to IEC 61000-4-4 • due to conductor-earth surge according to IEC 61000-4-5 • due to conductor-conductor surge according to IEC 61000-4-5 • due to high-frequency radiation according to IEC 61000- | 2 kV behavior criterion 2 1 kV behavior criterion 2 |
| conducted interference due to burst according to IEC 61000-4-4 due to conductor-earth surge according to IEC 61000-4-5 due to conductor-conductor surge according to IEC 61000-4-5 due to conductor-conductor surge according to IEC 61000-4-5 due to high-frequency radiation according to IEC 61000-4-6 | 2 kV behavior criterion 2 1 kV behavior criterion 2 140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1 |
| conducted interference due to burst according to IEC 61000-4-4 due to conductor-earth surge according to IEC 61000-4-5 due to conductor-conductor surge according to IEC 61000-4-5 due to conductor-conductor surge according to IEC 61000-4-5 due to high-frequency radiation according to IEC 61000-4-6 field-based interference according to IEC 61000-4-3 | 2 kV behavior criterion 2 1 kV behavior criterion 2 140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 |
| conducted interference • due to burst according to IEC 61000-4-4 • due to conductor-earth surge according to IEC 61000-4-5 • due to conductor-conductor surge according to IEC 61000-4-5 • due to conductor-conductor surge according to IEC 61000-4-5 • due to high-frequency radiation according to IEC 61000-4-6 field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 | 2 kV behavior criterion 2 1 kV behavior criterion 2 140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2 |
| conducted interference • due to burst according to IEC 61000-4-4 • due to conductor-earth surge according to IEC 61000-4-5 • due to conductor-conductor surge according to IEC 61000-4-5 • due to high-frequency radiation according to IEC 61000-4-6 field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 conducted HF interference emissions according to | 2 kV behavior criterion 2 1 kV behavior criterion 2 140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2 |
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| conducted interference • due to burst according to IEC 61000-4-4 • due to conductor-earth surge according to IEC 61000-4-5 • due to conductor-conductor surge according to IEC 61000-4-5 • due to high-frequency radiation according to IEC 61000-4-6 field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 conducted HF interference emissions according to CISPR11 field-bound HF interference emission according to CISPR11 | 2 kV behavior criterion 2 1 kV behavior criterion 2 140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2 Class A for industrial environment |
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| conducted interference due to burst according to IEC 61000-4-4 due to conductor-earth surge according to IEC 61000-4-5 due to conductor-conductor surge according to IEC 61000-4-5 due to high-frequency radiation according to IEC 61000-4-6 field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 conducted HF interference emissions according to CISPR11 field-bound HF interference emission according to CISPR11 Short-circuit protection, design of the fuse link manufacturer's article number of gS fuse for semiconductor protection at NH design usable of full range R fuse link for semiconductor protection at | 2 kV behavior criterion 2 1 kV behavior criterion 2 140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2 Class A for industrial environment Class B for the domestic, business and commercial environments |
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| conducted interference • due to burst according to IEC 61000-4-4 • due to conductor-earth surge according to IEC 61000-4-5 • due to conductor-conductor surge according to IEC 61000-4-5 • due to high-frequency radiation according to IEC 61000-4-6 field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 conducted HF interference emissions according to CISPR11 field-bound HF interference emission according to CISPR11 Short-circuit protection, design of the fuse link manufacturer's article number • of gS fuse for semiconductor protection at NH design usable • of full range R fuse link for semiconductor protection at cylindrical design usable • of back-up R fuse link for semiconductor protection at cylindrical design 14 x 51 mm usable • of back-up R fuse link for semiconductor protection at cylindrical design 22 x 58 mm usable | 2 kV behavior criterion 2 1 kV behavior criterion 2 140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2 Class A for industrial environment Class B for the domestic, business and commercial environments 3NE1802-0 5SE1350 3NE8017-1 3NC1450 |
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| conducted interference • due to burst according to IEC 61000-4-4 • due to conductor-earth surge according to IEC 61000-4-5 • due to conductor-conductor surge according to IEC 61000-4-5 • due to high-frequency radiation according to IEC 61000-4-6 field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 conducted HF interference emissions according to CISPR11 field-bound HF interference emission according to CISPR11 Short-circuit protection, design of the fuse link manufacturer's article number • of gS fuse for semiconductor protection at NH design usable • of full range R fuse link for semiconductor protection at cylindrical design usable • of back-up R fuse link for semiconductor protection at cylindrical design 14 x 51 mm usable • of back-up R fuse link for semiconductor protection at cylindrical design 22 x 58 mm usable manufacturer's article number of the gG fuse | 2 kV behavior criterion 2 1 kV behavior criterion 2 140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2 Class A for industrial environment Class B for the domestic, business and commercial environments 3NE1802-0 5SE1350 3NE8017-1 3NC1450 3NC2280 3NA6812; These fuses have a smaller rated current than the semiconductor relays 3NW6112-1; These fuses have a smaller rated current than the semiconductor |
| conducted interference • due to burst according to IEC 61000-4-4 • due to conductor-earth surge according to IEC 61000-4-5 • due to conductor-conductor surge according to IEC 61000-4-5 • due to high-frequency radiation according to IEC 61000-4-6 field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 conducted HF interference emissions according to CISPR11 field-bound HF interference emission according to CISPR11 Short-circuit protection, design of the fuse link manufacturer's article number • of gS fuse for semiconductor protection at NH design usable • of full range R fuse link for semiconductor protection at cylindrical design usable • of back-up R fuse link for semiconductor protection at cylindrical design 14 x 51 mm usable • of back-up R fuse link for semiconductor protection at cylindrical design 22 x 58 mm usable manufacturer's article number of the gG fuse • at NH design usable | 2 kV behavior criterion 2 1 kV behavior criterion 2 140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2 Class A for industrial environment Class B for the domestic, business and commercial environments 3NE1802-0 5SE1350 3NE8017-1 3NC1450 3NC2280 3NA6812: These fuses have a smaller rated current than the semiconductor relays 3NW6112-1: These fuses have a smaller rated current than the semiconductor relays 3NW6212-1: These fuses have a smaller rated current than the semiconductor relays |
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• of DIAZED fuse usable

5SB4111; These fuses have a smaller rated current than the semiconductor relays

• of NEOZED fuse usable 5SE2335; These fuses have a smaller rated current than the semiconductor relays

Approvals Certificates

General Product Approval

EMV

Confirmation











Test Certificates Railway other **Environment**

Special Test Certificate

Type Test Certific-ates/Test Report

Confirmation



Special Test Certificate

Environmental Confirmations

Further information

Information on the packaging

https://support.industry.siemens.com/cs/ww/en/view/109813875

Information- and Downloadcenter (Catalogs, Brochures,...)

https://www.siemens.com/ic10

Industry Mall (Online ordering system)

https://mall.industry.siemens.com/mall/en/en/Catalog/product?mlfb=3RF2340-1AA24

Cax online generator

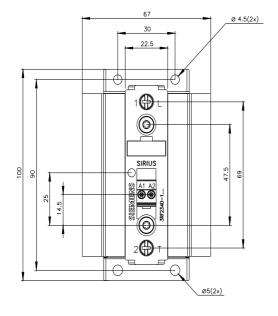
http://support.automation.siemens.com/WW/CAXorder/default.aspx?lang=en&mlfb=3RF2340-1AA24

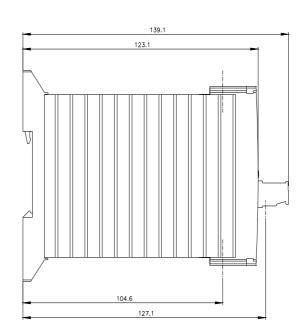
Service&Support (Manuals, Certificates, Characteristics, FAQs,...)

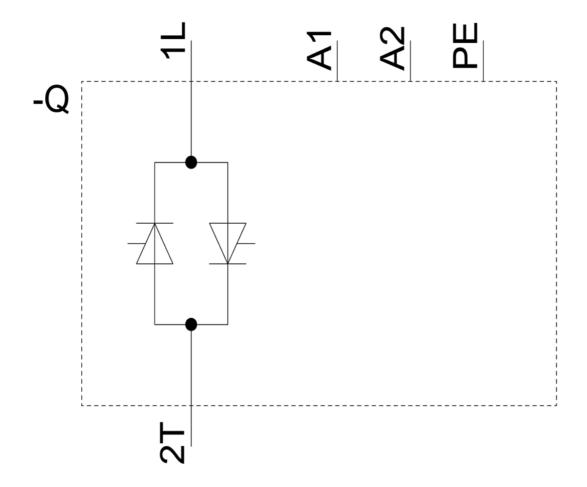
https://support.industry.siemens.com/cs/ww/en/ps/3RF2340-1AA24

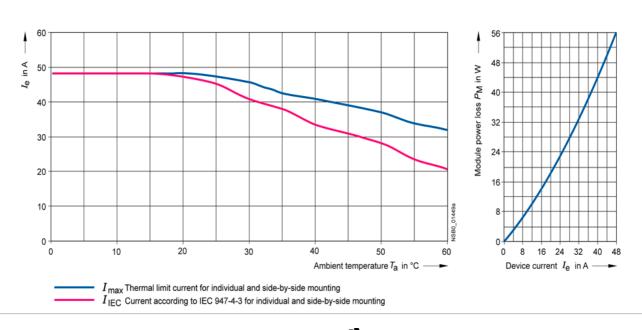
Image database (product images, 2D dimension drawings, 3D models, device circuit diagrams, EPLAN macros, ...)

http://www.automation.siemens.com/bilddb/cax_de.aspx?mlfb=3RF2340-1AA24&lang=en









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